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Optically Anisotropic Media: New Approaches to the Dielectric Function, singular axes, Microcavity Modes and Raman Scattering Intensities

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Six out of seven crystal systems are optically anisotropic and birefringent. We review recent insight that biaxial crystals generally exhibit four singular axes (or exceptional points) which can pairwise degenerate for special cases. Planar anisotropic microcavities are discussed as effectively biaxial systems and we predict exceptional points and demonstrate partially coalesced eigenstates. Also the general form of the dielectric function of anisotropic crystals based on individual dipole oscillators for phonon and electronic resonance is discussed. The impact of birefringence on Raman scattering intensities has been historically either ignored or modeled incorrectly. A recent theory for uniaxial and biaxial crystals explains experimental Raman scattering intensities for excitation off the principal directions without free parameters, allowing the unambiguous determination of the Raman tensor components. The above points are demonstrated and relevant in particular for the currently technologically important materials GaN, ZnO (uniaxial) and β -Ga₂O₃ (biaxial).

Formula for the Raman scattering intensity as a function of incoming and outgoing polarization and the Raman tensor seen through birefringent crystal (calcite).

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1 Introduction There exist seven crystal systems, cubic, tetragonal, hexagonal, trigonal, orthorhombic, monoclinic and triclinic. It is well known that the dielectric tensor for a suitable high symmetry choice of coordinate sys-

tem has the forms given in Table 1; the optical character is denoted as isotropic, uniaxial (for tetragonal, hexagonal, trigonal crystals) or biaxial (for orthorhombic, monoclinic and triclinic crystals) [1]. Optically isotropic (cubic) crys-

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Table 1 General form of the dielectric tensor ϵ for the 7 crystal systems, maximum number of optic axes N (for complex ϵ , indices 's' and 'n' denote singular and normal optic axes) and number of different indices of refraction of these axes ν .

crystal system	optical symmetry	ϵ	examples	N	ν
cubic	isotropic	$\begin{pmatrix} a & 0 & 0 \\ 0 & a & 0 \\ 0 & 0 & a \end{pmatrix}$	Si, GaAs, MgO, CuI	∞_n	1
tetragonal hexagonal trigonal	uniaxial	$\begin{pmatrix} a & 0 & 0 \\ 0 & a & 0 \\ 0 & 0 & c \end{pmatrix}$	CuGaSe ₂ GaN, ZnO Bi ₂ Se ₃	1_n	1
orthorhombic	biaxial	$\begin{pmatrix} a & 0 & 0 \\ 0 & b & 0 \\ 0 & 0 & c \end{pmatrix}$	Sb ₂ Se ₃ , SrSO ₄	4_s	1
monoclinic	biaxial	$\begin{pmatrix} a & 0 & d \\ 0 & b & 0 \\ d & 0 & c \end{pmatrix}$	β -Ga ₂ O ₃ , anthracene	4_s	2
triclinic	biaxial	$\begin{pmatrix} a & d & e \\ d & b & f \\ e & f & c \end{pmatrix}$	K ₂ Cr ₂ O ₇ , tetracene	4_s	4

tals can also become optically anisotropic (uniaxial or biaxial) in the presence of non-hydrostatic strain or in the presence of (anisotropic) surface layers.

Here we review recent insights into the optical properties of anisotropic crystals. The general form of the dielectric tensor and its deconstruction into the dipole contributions of lattice and electronic oscillators oriented in different directions is discussed. Also we point out that in general biaxial materials possess *four* "singular" optic axes which can pairwise degenerate for special cases, in particular when the dielectric tensor is real (transparency regime). The presence of four "Singulartitäts- oder Windungsachsen" in biaxial, absorbing crystals has been pointed out first by W. Voigt [2] (Fig. 1) in 1902 [8–10]. For these directions the eigenstate is left- or right-circular polarized and accordingly allows the propagation of so-called Voigt waves.

The case of transparent biaxial crystals is still very interesting [11], historically well-known for the effect of conical refraction [12, 13], an optical singularity [14] due to the double cone structure of the index of refraction around the optic axes. Recent experiments also discuss the spin and angular momentum control of beams using conical refraction [15]. Here, however, we focus on the regime where the imaginary part of the dielectric function cannot be neglected.

The discovery of singular axes was preceded by Laspeyres who stated in 1880 that (in modern terms) the main axes of the real and imaginary parts of the dielectric tensor generally do not coincide [16, 17]. Before that Babinet had worked on the relation of the direction of

fastest wave and strongest absorption [18]. Voigt's work of 1884 [19] on weakly absorbing (biaxial) crystals is written in a pre-Maxwell formulation. For weak absorption it was stated that two optic axes exist with different attenuation of two elliptically polarized waves. The orientation of absorption axes and their symmetry for orthorhombic and monoclinic crystals was also discussed in 1887 by Becquerel [20]. The problem was then approached in the well known paper of Drude [21], summarizing his thesis as Voigt's doctoral student, on reflection and refraction at the interface of absorbing crystals. Here Drude develops a general treatment but states that optic axes do not exist in absorbing crystals of the orthorhombic system [22]. A summary of early crystal optics around this time can be found in [23].

Figure 1 Woldemar Voigt (1850–1919) [24].

Finally in [8] Voigt uses the "Maxwell-Hertz" formulas and states that the main axes of the real and the imaginary parts are differently oriented in general, naming them polarization and absorption axes. The general case for a symmetric dielectric tensor and weak absorption is treated. Experimental observations on orthorhombic (andalusite), monoclinic (epidote) and triclinic (axinite) crystals are discussed and explained. He revisited this topic several times [25–29].

Further work on singular axes has been reported e.g. in [30–41], but we feel that parts of the optics community have largely forgotten about singular axes. A recent analysis provided an in depth view of the spectral dispersion and possible degeneracies of the singular axes [42] for monoclinic gallia as model system.

We note that in a more general framework such degeneracies of non-Hermitian Hamiltonians [43–46] with

chiral and coalesced eigenfunctions are termed *exceptional points* [47–52] and have been found in coupled dissipative dynamical systems [53], mechanical problems [54], electronic circuits [55], microwave cavities [56], gyrokinetics of plasmas [57], coupled fiber-ring resonators [58], atomic spectra [59,60], coupled quantum cascade microdisk lasers [61], photonic crystals [62], inhomogeneous gain media [63], optical lattices of driven cold atoms [64] and plasmonic waveguides [65]. We also point to literature on exceptional points with a degeneracy larger than two [62,66–68].

The associated effects of birefringence in uniaxial and biaxial crystals affect Raman scattering for crystal orientations off the principal axes, a problem first posed by Michalke in 1938 [69]. After several works, the topic was dropped unresolved and Raman scattering intensities from optically anisotropic crystals not oriented along a principal direction were explained with the help of unphysical parameters, e.g. by including an ad hoc complex phase factor into the technically real Raman tensor (in the transparency regime) for hexagonal (and thus uniaxial) GaN [70] or ZnO [71] or several phase factors for orthorhombic (and thus biaxial) black phosphorus [72] or denoting the squares of Raman tensor elements for (monoclinic) naphthalene and anthracene [73]. Only recently, a theory was conceptualized to explain Raman scattering intensities for all crystal systems taking birefringence properly into account [74]; these results are for example highly relevant for the technologically interesting non-polar and semi-polar orientations of wurtzite materials [75].

From the materials ZnO and GaN microcavities have been built that enable strong light-matter coupling and condensation of exciton-polaritons at elevated temperature and thus macroscopic quantum states and new laser mechanisms up to room temperature. A particularly interesting case, related to the previously discussed biaxial crystal optics problems, are cavities for which the optic axis is tilted (typically perpendicular) to the cavity layer direction. Such "effectively biaxial" inhomogeneous media are discussed at the end of this review. We predict the occurrence of exceptional points and show first experimental evidence for non-orthogonal (partially coalesced, elliptically polarized) eigenstates in such cavity. We note that Voigt waves have been discussed in composite media from two uniaxial materials with relative tilt of their optic axes in [37].

The calculations for this paper have been executed using Mathematica [76], except the calculations for the planar microcavities which have been executed using MATLAB [77].

2 Dielectric Function Only for a few optically anisotropic materials the dielectric function has been reported in a wide wavelength range. For monoclinic gallia (β -Ga₂O₃) the dielectric tensor has been determined using generalized spectroscopic ellipsometry in the energy range 0.5–8.5 eV [78] on crystals purchased from Tamura Corpora-

tion [79]. An extension to the infrared phonon regime was reported in [80] down to about 0.03 eV and in [81] down to about 0.006 eV. In [82,83] a method in the infrared based on external and total internal reflection was reported in order to determine phonon oscillator parameters in monoclinic crystals from reflectivity spectra.

Extending an approach of [84–86] beyond Lorentz oscillators, the dielectric response is considered (in first order) as the combined effect of various spectrally broadened and spectrally overlapping oscillators with their dipoles oriented with respect to the coordinate system of the (relative) dielectric tensor (generally $\epsilon_{ij} = \delta_{ij} + \chi_{ij}$),

$$\epsilon = \mathbb{1} + \sum_{i=1}^N R(\phi_i, \theta_i) \chi'_i R^{-1}(\phi_i, \theta_i), \quad (1)$$

χ'_i being the susceptibility (tensor) of the i^{th} excitation and ϕ_i and θ_i denoting the Euler angles, which are in general different for each excitation, and R being the rotation matrix [80]. Eq. (1) is valid in general and necessary for a triclinic material. Allowed dipole orientations are restricted by crystal symmetry and allow to simplify (1) to

$$\epsilon = \mathbb{1} + \sum_{i=1}^{N_y} \chi_{i,y} + \sum_{j=1}^{N_{xz}} R(\phi_j) \chi'_{j,xz} R^{-1}(\phi_j), \quad (2)$$

for a monoclinic material (symmetry forcing dipoles to be polarized either along y or perpendicular to y , in the (x, z) -plane), and to

$$\epsilon = \mathbb{1} + \sum_{i=1}^{N_x} \chi_{i,x} + \sum_{j=1}^{N_y} \chi_{j,y} + \sum_{k=1}^{N_z} \chi_{k,z}, \quad (3)$$

for an orthorhombic material [80].

The validity of (2) for the application to β -Ga₂O₃ in the phonon range [80,81] and for electronic transitions [80] has been confirmed. In Fig. 2 the unit cell of β -Ga₂O₃ is shown with the y -direction perpendicular to the (x, z) -plane containing the non-rectangular angle.

The experimentally found dipole orientations (visualized in Fig. 3) coincide with theoretically calculated ones very closely and allow deeper insights in the atomistic origin of the various lattice and electronic contributions [80]. For the phonon modes also the (relative) oscillator strengths are well reproduced by theory. We note that a modified Lyddane-Sachs-Teller relation for monoclinic and triclinic materials has been proposed in [87].

In heteroepitaxy rotation domains can occur when the symmetries of substrate and epilayer do not match [88, 89]. The associated averaging of the dielectric tensor over various domain orientations can modify the effective optical properties. In the case of epitaxy of β -Ga₂O₃ on [00.1]-oriented (c -plane) Al₂O₃ six different (201)-oriented domains occur [90] and the resulting effective medium (for measurement averaging over many domains) is uniaxial [80,91].

Figure 2 Unit cell of β -Ga₂O₃ (oxygen atoms are shown in red, gallium atoms as green (octahedral-like coordination) and blue (tetrahedral-like coordination)) and its orientation in the coordinate system chosen in Table 1: $[100] \parallel x$, $[010] \parallel y$; the angle between $z = x \times y$ and $[001]$ is $103.7^\circ - \pi/2$. The $(\bar{2}01)$ plane is indicated.

Figure 3 Arrows depicting the orientation and relative amplitudes (the strongest transitions is scaled to unit length) of the dipole moments in the (x, z) -plane ($x \parallel [100]$) of β -Ga₂O₃ for various UV electronic (excitonic) transitions (top row) and different IR phonon modes (bottom row). Labels refer to notation in [80]. The left (right) column displays experimental (theoretical) results.

3 Singular Axes

3.1 Spectral Dispersion The analysis of the dielectric function of Ga₂O₃ put forward in [42] allows to calculate the angular position of the singular axes. In general, the complex dielectric tensor of orthorhombic, monoclinic and triclinic crystals leads to *four* singular axes. Such axes were first considered for orthorhombic material [8,30]

and have been named *Windungsachsen* initially [8] because their eigenstates are circularly polarized. The analytical treatment of the related problem from Maxwell's equations shows that orthorhombic, monoclinic and triclinic crystals can generally be distinguished optically from the degeneracy of the (complex) indices of refraction for these axes, exhibiting a single, 2 or 4 different values, respectively [42] (see Table 1). The three uniaxial crystal systems (tetragonal, hexagonal, trigonal) cannot be distinguished optically since they possess the same form of the dielectric tensor and remain uniaxial in the absorption regime [42]. We note that also assemblies of nanocrystals [92] or rare-earth doped crystals [39,93] represent examples of (effective) birefringent absorptive media. Analytical solutions for orthorhombic and monoclinic crystals can be found in [42]; we point to previous discussions of the orientational dependence of the complex index of refraction [94,95].

Figure 4 Stereographic projection of the angular positions of the singular axes in β -Ga₂O₃ as a function of photon energy. Crystallographic planes (marked by open circles) are labelled.

In Fig. 4 the spectral dispersion of the direction of the singular axes in monoclinic Ga₂O₃ is depicted. We note that the angular position of optic axes over a wider spectral range (in the transparency regime) has been reported previously, e.g. [96], but Ref. [42] represents the first report of the spectral dispersion of singular axes (in the absorption regime). The (x, z) symmetry plane perpendicular to the $[010]$ - (y -) direction is obvious. At the onset of absorption (point 'A' in Fig. 4, $E = 4.78$ eV) the two optic axes from the transparency regime start to exhibit significant splitting into the four singular axes. 'B' denotes a range ($E \approx 7.23$ – 7.33 eV) of "almost" uniaxial degeneracy close to the $[100]$ -direction. At two spectral points (points 'C', $E = 8.14$ eV and 'D', $E = 8.37$ eV) one pair of singular axes degenerates, forming a "normal" (but absorptive) optic axis, rendering the material triaxial [42], a case also considered in [41]. A more detailed discussion can be found in [42].

Figure 5 The Stokes vector component S_3 (circular polarization) in the (ϕ, θ) -plane (in units of π) in false colors. The singular axes are at $|S_3| = 1$. The contour with $S_3 = 0$ (linear polarization) is shown as thick black lines. (b) depicts the situation for monoclinic ($\epsilon_{xz} \neq 0$) β -Ga₂O₃ at photon energy $E = 6.20$ eV. (a) depicts a fictitious triclinic material with the same dielectric tensor but additionally $\epsilon_{xy} = \epsilon_{xz}$. (c) depicts a fictitious orthorhombic material with the same dielectric tensor but $\epsilon_{xz} = 0$. The white dots indicate the angular position of the singular axes.

3.2 Eigenstates The angular distribution of the circular polarization component of the eigenmodes (Stokes vector component S_3) is depicted in Fig. 5b for β -Ga₂O₃ at a particular photon energy ($E = 6.20$ eV) [97]. The angles θ and ϕ denote the rotation of the crystal around the y - and z -axis, respectively, as defined in [42]. At the position of the singular axes, it is ± 1 , along the thick black lines it is zero (linear polarization). In terms of the notation of [98–100] the singular axes are ‘C-points’ and the lines of linear polarization are ‘L-lines’.

The additional symmetry changes for a biaxial material that is less symmetric and triclinic (Fig. 5a) or more symmetric and orthorhombic (Fig. 5c) is shown for comparison, by setting $\epsilon_{xy} = \epsilon_{xz}$ and $\epsilon_{xz} = 0$, respectively, for a fictitious similar material.

In Fig. 6 the situation is depicted for the crystallographic y -direction. At $E = 6.59$ eV, the Stokes vector component is $S_3 = -0.997$, i.e. the direction represents ‘almost’ a singular axis. The spectral dependence of the projection of the Stokes vector on the (S_1, S_2) -plane is shown in Fig. 6a. In Fig. 6b, the spectral dependence of S_3 is shown together with the real and imaginary part of the index of refraction and $|n_1 - n_2|$ (n_1 and n_2 refer to the complex indices of the two eigenmodes for a given direction and energy). At the energy $E = 6.59$ eV the real parts of n are identical while the imaginary parts of n are only close. A more detailed discussion and Stokes vector analysis for eigenstates in other directions can be found in [42].

The change of the eigenvectors of the (transverse) fields $\mathbf{D}_a$ and $\mathbf{D}_b$ from orthogonal to parallel (at *exactly* the singular axis, $\mathbf{D}_a$ and $\mathbf{D}_b$ are degenerate (coalesced) and circularly polarized) is continuous. This can be seen from the (absolute value of the complex) scalar vector product (dot product) $\mathbf{D}_b^* \cdot \mathbf{D}_a$ as depicted in Fig. 7. Its maximum at the singular axes is conical. For the case $\Im \epsilon = 0$, $\mathbf{D}_b^* \cdot \mathbf{D}_a$ vanishes for all orientations, which is well known. We note that non-orthogonal states that are not completely coalesced ($0 \leq \mathbf{D}_b^* \cdot \mathbf{D}_a \leq 1$) correspond to elliptically polarized states (cmp. Figs. 5b and 7a).

For the absorption case, the polarizing properties of the biaxial crystal change with orientation from a homogeneous Jones matrix (with orthogonal eigenvalues) to an inhomogeneous Jones matrix, described with the inhomogeneity parameter $\eta = |\mathbf{E}_b^* \cdot \mathbf{E}_a| \leq 1$ as defined in [101]. We note that the orientational dependence of η looks practically identical to Fig. 7a.

3.3 Complex Index of Refraction The angular analysis of the two complex indices of refraction shows that besides $\Re n_1 - \Re n_2 = 0$ and $\Im n_1 - \Im n_2 = 0$ at the angular positions of the singular axes, $\Re n_1 - \Re n_2$ is zero along continuous angular arcs limited by two singular axes (Fig. 8a) and $\Im n_1 - \Im n_2$ vanishes along different arcs, connecting two different singular axes (Fig. 8b). The $\Re n_1 - \Re n_2 = 0$ arcs run in the vicinity of the related optic axis for the case $\Im \epsilon = 0$ (cmp. also Fig. 11e)

Figure 6 (a) Energy dependence of the Stokes vector (stereographic projection (S_1, S_2), $S_3 = \pm 1$ is in the center of the graph) for the y -direction ([010]) (same color scale as in Fig. 4). (b) Spectral dependence of the real and imaginary parts of the index of refraction, their absolute difference and of the Stokes vector component S_3 for this direction. The energy $E = 6.59$ eV, where $|n_1 - n_2|$ is close to zero and S_3 is close to -1 , is denoted with a vertical dashed line.

as pointed out in [28]. The $\Im n_1 - \Im n_2 = 0$ arcs run in the vicinity of the related "absorption" axis for the case $\Re \epsilon = 0$. Another visualization of this situation are the three-dimensional representations of $\Re n$ and $\Im n$ in Fig. 9a,b which look as described by Drude [102] like "eine Fläche mit zwei Schalen [...], die] längs gewisser Kurvenstücke, die bei monoklinen und triklinen Krystallen unsymmetrisch zu den Coordinatenebenen liegen, zusammenhängen." [103]. A modern theory of this phenomenon is formulated with Hamiltonians in [104]. It was shown for (monoclinic) Nd:YCOB ($\text{YCa}_4\text{O}(\text{BO}_3)_3$), prepared in the form of a spherical crystal, a geometry already studied for ruby [105] and used by Raman [106], that there exists an angular range for which the absorption coefficient is independent of the polarization [39].

For comparison the situation for artificially setting $\Im \epsilon = 0$ is depicted in Fig. 9c,d, displaying the double cone (diabolic) structure around one of the (two conventional) optic axes. We note that a similar structure has

Figure 7 (a) The dot product $|D_b^* \cdot D_a|$ of the eigenvectors; while small for most directions, it becomes 1 on the singular axes. The white dots indicate the angular positions of the singular axes. (b) 3D visualization around one of the singular axes.

been found for heavy and light hole dispersions in strained materials [107].

In Fig. 10 the typical bifurcations [108] at an exceptional point are shown by varying artificially the imaginary part of the dielectric function. Also the analogue exceptional point for negative imaginary part appears ($\gamma = -1$ in Fig. 10a) that would occur in the presence of gain.

3.4 Reflection and Transmission The problem of reflection and transmission of circularly polarized waves from a crystal cut perpendicular to a singular axis has already been brought up in [29]. In the Appendix 7.1 the current treatment of reflection (and transmission) from a planar interface of a biaxial material is sketched and the result shall be shown here for $\beta\text{-Ga}_2\text{O}_3$ at the energy $E = 6.20$ eV. The reflection coefficients for circularly polarized light, defined via

$$\begin{pmatrix} l_r \\ r_r \end{pmatrix} = \begin{pmatrix} R_{ll} & R_{lr} \\ R_{rl} & R_{rr} \end{pmatrix} \begin{pmatrix} l_i \\ r_i \end{pmatrix}, \quad (4)$$

Figure 8 The difference of the two indices of refraction as (a) $|\Re n_1 - \Re n_2|$ and (b) $|\Im n_1 - \Im n_2|$ as a function of propagation direction for β -Ga₂O₃ at a photon energy of $E = 6.20$ eV. The white lines indicate the zeros, the white dots denote the angular positions of the singular axes, the yellow (red) dots the related optic axes for the case $\Im \epsilon = 0$ ($\Re \epsilon = 0$).

where l_i, r_i (l_r, r_r) denote the incoming (reflected/outgoing) left- and right-circular polarized waves, are depicted (absolute values) in Fig. 11a–c.

A left-circularly polarized wave is mostly reflected as right-polarized wave and vice versa, the related reflection coefficients are termed R_{lr} and R_{rl} and are found identical for all angles (Fig. 11a). A small part suffers mode conversion and comes back for incoming left-circular wave as left-circular reflected wave, its reflectivity denoted by R_{ll} (Fig. 11b); R_{rr} is defined accordingly (Fig. 11c). For each of the left or right incoming waves four singular directions lead to fully circularly polarized light (either R_{ll} or R_{rr} are zero and $|S_3| = 1$). In particular, when a left-circular wave ($S_3 = -1$) falls onto a singular axis with $S_3 = +1$ (cmp. Fig. 5b), $R_{ll} = 0$ and the reflected wave is purely right-circular ($S_3 = +1$). If (artificially) the absorption is set to zero ($\Im \epsilon = 0$), $R_{ll} = R_{rr}$ with its zeros on the optic axes as visualized in Fig. 11d–f.

We note that the *exact* angular positions of the singular axes are strictly never numerically evaluated. However, the eigenvectors of the (transverse) fields D_a and D_b , i.e. ϵE_a and ϵE_b with the fields in (9), change continuously from orthogonal to parallel (at *exactly* the singular axis D_a and D_b are degenerate) (cmp. Fig. 7). We note that at *exactly* the singular axis the equations (14) and (15) are undetermined, but already in the vicinity of the singular axes, the eigenvectors are non-orthogonal and the transmission coefficients derived from the boundary conditions (14) and (15) are unphysical.

Instead a matrix approach for the propagation (Appendix 7.2) can be used that completely avoids the (technically unnecessary) vector decomposition into eigenstates within the biaxial medium. The electric field *entering* the biaxial medium is subject to “unconventional” propagation (see next section). The results for the reflection coefficients, as depicted in Fig. 11, remain valid and for the transmission physically reasonable values are obtained.

3.5 Propagation From the previous section, it is clear that a left- and a right-circularly polarized wave can enter the biaxial crystal when they fall onto a singular axis. Let us look at a singular axis that is right-polarized ($S_3 = +1$). Then the polarization of the right-circular wave, which is the eigenstate, remains unchanged while the wave propagates through the crystal (Voigt wave, Fig. 12a). The left-circular wave is asymptotically converted into a right-circular wave as also depicted in Fig. 12a. From Fig. 12b it can be seen that left-circular wave actually suffers the smaller absorption. This behavior has been already discussed in [32, 109] and experimental results have been reported for KGd(WO₄)₂:Nd [110]. Here it becomes clear that the left-circular fraction suffers the same attenuation as the right-circular, i.e. $T_{ll} = T_{rr}$, their definition being similar to (4),

$$\begin{pmatrix} l_t \\ r_t \end{pmatrix} = \begin{pmatrix} T_{ll} & T_{lr} \\ T_{rl} & T_{rr} \end{pmatrix} \begin{pmatrix} l_i \\ r_i \end{pmatrix}, \quad (5)$$

l_t, r_t denoting the circularly polarized transmitted waves; for the calculation of the matrix elements in (5) the matrix T (28) from Appendix 7.2 is used. For the left-circular incoming wave *additionally* a right-circular wave exists ($T_{rl} \neq 0$) which enhances the transmittance for the initially left-circular wave (Fig. 12b). We note that since the right-circular wave passes without mode conversion, $T_{lr} = 0$. At the thickness ($d \approx 0.537 \mu\text{m}$) where $S_3 = 0$, also $T_{ll} = T_{rl}$.

In Fig. 13 shows the Stokes vector of transmitted light propagating in the crystallographic y -direction at $E = 6.59$ eV when this direction is close to a $S_3 = -1$ singular axis (cmp. Fig. 6). Mode conversion occurs for both left- and right-circular waves but the incident left-circular polarized light remains at least within the range of negative S_3 .

Figure 9 Three-dimensional plot of (a) $\Re n$ and (b) $\Im n$ as a function of propagation direction (for clarity only for the hemisphere $0 \leq \phi \leq \pi$) for β -Ga₂O₃ at a photon energy of $E = 6.20$ eV. The connections of the upper and lower branch correspond to the white lines in Fig. 8. (c) Three-dimensional plot of $n = \Re n$ when the imaginary part of the dielectric function for β -Ga₂O₃ at a photon energy of $E = 6.20$ eV is artificially set to zero as a function of propagation direction. (d) Same as (c) but zoomed to one of the optic axes, displaying the diabolic point.

Figure 10 (a) Real and (b) imaginary values of the squares of the indices of refraction for the orientation of a singular axis (same as in Fig. 7) in β -Ga₂O₃ at a photon energy of $E = 6.20$ eV and setting artificially the dielectric function to $\tilde{\epsilon} = \Re \epsilon + \gamma \Im \epsilon$. (c) depicts the two indices in the complex plane depending parametrically on γ . $\gamma = 1$ represents the actual dielectric function and the exceptional point is indicated by the arrows; negative values of γ or $\Im n^2$ denote gain regime.

4 Planar microcavities with anisotropic media

A planar microcavity is a layered system consisting of a

cavity medium (typically of thickness $(2n + 1) \times \lambda/2$,

Figure 11 The reflection coefficients of circularly polarized light for normal incidence from β -Ga₂O₃ at $E = 6.20$ eV, (absolute values) (a) $R_{lr} = R_{rl}$, (b) R_{ll} and (c) R_{rr} . The white dots indicate the angular positions of the singular axes. (d)–(f) show the same quantities for setting (artificially) $\Im \epsilon = 0$ (leading to $R_{ll} = R_{rr}$); in this case the white dots indicate the angular positions of the conventional optic axes.

$n = 0, 1, \dots$) sandwiched between two distributed Bragg reflector (DBR) mirrors. This way the growth direction per se introduces a preferred direction and rotational symmetry. The dispersion of the cavity mode is a fundamental

property of such cavity. In [111] the effect of an uniaxial cavity material and the orientation of its optic axis relative to the cavity axis was investigated theoretically. If the optic axis and the cavity axis are aligned no particular effects are

Figure 12 (a) The Stokes vector of the transmitted light (normal incidence, $E = 6.20$ eV) from a Ga_2O_3 slab cut perpendicular to a $S_3 = +1$ singular axis (same as in Fig. 7) as a function of the slab thickness for incoming right- (left-) circularly polarized light shown as red solid (blue solid) curve. For incoming left-circular light, the Stokes vector components S_1 and S_2 are shown as dashed and dashed-dotted lines, respectively. (b) Transmitted intensity for right-circular light (T_{rr} , red curve) and left-circular light exiting as left-circular ($T_{ll} = T_{rr}$, blue curve) and right circular (T_{rl} , black curve). We note that $T_{lr} = 0$. The vertical dashed line indicates the thickness for which $T_{ll} = T_{rl}$.

present. For a general orientation of the optic axis, when it is tilted with respect to the stacking direction, the rotational symmetry of the system does not hold anymore. In this case the medium contains two distinguished directions and is effectively biaxial.

This results at least in the TE- and TM-polarized cavity-photon mode(s) not coinciding at normal propagation angle (Fig. 14). Such effect has been observed experimentally for microresonators with nonpolar GaN-based [112–114] and ZnO-based [115] cavities (Fig. 15). The typical setup of such cavity is a homoepitaxial bottom DBR, e.g. $[11\bar{2}0]$ (a -plane) oriented $[112]$ or $[10\bar{1}0]$ (m -plane) oriented $[113]$ (Al,Ga)N/GaN or m -plane oriented (Mg,Zn)O/ZnO [115], a cavity with the wurtzite c -axis in-plane and a top mirror (dielectric or epitaxial); such system is effectively orthorhombic. Generally, also a tilted c -axis (unless parallel to the growth direction) results in a case of reduced symmetry. For the epitaxial growth of such structures, strain relaxation is important due to the lattice mismatch between the various layers due to the dependence of the lattice constants of $(\text{Al}_x\text{Ga}_{1-x})\text{N}$ or $(\text{Mg}_x\text{Zn}_{1-x})\text{O}$ on the alloy concentration. We note that the said nitride and oxide alloy systems behave rather differently since $\partial c/\partial x \times \partial a/\partial x$ is positive or negative, respectively [75].

Figure 13 (a) Stokes vector component S_3 of the transmitted light (normal incidence, $E = 6.59$ eV) from a Ga_2O_3 slab cut perpendicular to the y -axis (cmp. Fig. 6) as a function of the slab thickness d for incoming right- (left-) circularly polarized light shown as red (blue) curves. (b) Stokes vector of transmitted light for incoming right- (left-) circularly polarized light shown as red solid (blue solid) curves and $d = 0\text{--}4$ μm .

Based on a Maxwell approach to the propagation of electromagnetic waves with complete polarization treatment, complex mode energies can be numerically determined as singularities of the system and the respective polarization is obtained from the matrix kernel [116]. A cavity photon mode is found to be split into two modes, whose polarization states are generally elliptical and thus non-orthogonal to each other. Depending on the cavity thickness, those two modes can be degenerate (same energy and broadening) at finite in-plane wave vectors which correspond to propagation nearly but not exactly along or perpendicular to the projection of the optic axis in the cavity plane. While the modes have linear orthogonal polarizations at zero in-plane wave vector (vertical emission), these degeneracy points are circularly co-polarized and represent exceptional points [117]. In particular, the degeneracy points of energy and broadening occur pair-wise (Fig. 16). The connecting line between them reveals a discontinuity of the mode broadening and polarization. Starting from the

Figure 14 Dispersion versus propagation angle of the TE- (black lines) and TM- (red lines) polarized cavity-photon mode for two different directions of the optic axis of the uniaxial cavity material within the cavity plane. The cavity-photon mode which is connected to the ordinary wave within the cavity is shown as solid line whereas the extraordinary one is shown as dashed line (for positive birefringence) or as dotted line (for negative birefringence).

exceptional points, arcs of constant energy and broadening (shown as solid red lines in Fig. 16, cmp. Fig. 8) extend in the $k_{||}$ -plane. The linear polarization is predicted to exhibit a vortex-like structure (Fig. 17) in the momentum space around the degeneracies [117].

For a m -plane (Mg,Zn)O/ZnO λ -microcavity we have measured polarized transmission (Fig. 15c). The Stokes vector as a function of energy and angle of incidence is depicted for two in-plane orientations of the c -axis (rotated by $\pm 30^\circ$ relatively to the situation in Fig. 14a). The finite circular component (S_3) of about ± 0.15 at its extrema indicates non-orthogonal, partially coalesced eigenstates as predicted. Further design of cavity parameters, in particular of the cavity thickness, should move the exceptional points into the light cone and make fully circularly polarized states observable.

We like to mention here that chiral modes at exceptional points have also been found for whispering gallery resonators [118, 119].

5 Raman Scattering

5.1 Treatment of Birefringence The problem of Raman scattering in anisotropic crystals has been realized early on [69] and the failure of the conventional approach in birefringent materials (off a principal axis) has been corroborated in [120] 50 years ago. The analysis of such Raman scattering intensities was deemed "pointless" [121] and the effect of birefringence "predictably catastrophic" [122]. However, we attribute this only to the lack of including correct crystal optics into Raman theory. The closest to a solution is the work of Rulmont et

Figure 15 (a) Cross-section scanning electron microscopy image of m -plane $n_1 \times [\text{ZnO}/\text{Mg}_x\text{Zn}_{1-x}\text{O}]$ DBR / ZnO / $n_2 \times [\text{ZnO}/\text{Mg}_x\text{Zn}_{1-x}\text{O}]$ DBR microcavity ($n_1 = 18$, $n_2 = 22$, $x \approx 0.22$). (b) Macroreflectivity measurements of a m -plane cavity ($n_1 = 15$, $n_2 = 16$) for normal incidence, unpolarized (black, vertically shifted for clarity) and linear polarization resolved (red, polarization perpendicular to the c -axis, and blue parallel to the c -axis) spectra. (c) (Normalized) Stokes vector components for the angular dispersion of polarized transmission through a non-polar m -plane (Mg,Zn)O/ZnO λ -microcavity. The c -axis is in-plane and azimuthally rotated by $\phi = \pm 30^\circ$ as labelled with respect to the direction normal to the angular scan ($\phi = 0^\circ$ relates to the configuration in Fig. 14a).

Figure 16 Dispersion of energy E and broadening γ depending on the in-plane wave vector $k_{||}$. The cavity is uniaxial with the optic axis along y and the optical cavity thickness (along z) is larger than half the central wavelength of the surrounding Bragg mirrors. The mode degeneracies of E and γ are shown as red dots in the projection, the arcs of constant energy and broadening are shown as solid red lines.

Figure 17 Polarization Stokes vector components of one cavity photon mode depending on the in-plane wave vector $k_{||}$. The cavity is uniaxial with the optic axis along y and the optical cavity thickness (along z) is larger than half the central wavelength of the surrounding Bragg mirrors. The mode degeneracies are the four circularly polarized spots (S_3) which are accompanied by a discontinuity of the linear polarization (see S_1).

al. [123,124]. In [125] the effect of birefringence on the Raman scattering from black phosphorus was modeled for a special scattering geometry. The concept of our reported theory [74] is to consider for a crystal of arbitrary symmetry the mode conversion from linear incoming polarization to varying elliptical/circular polarization along the path of the exciting radiation into the sample and likewise for the path of the scattered radiation back out of the sample. The Raman scattering event in between is correctly described (in the transparency regime) with a real-valued Raman tensor. Averaging is necessary over the excitation laser intensity distribution and excitation depth (or sample thickness). This scheme allows to determine the elements of the Raman tensor and their (relative) signs.

5.2 Uniaxial Crystals The effect of birefringence Δn is visualized for (optically uniaxial) wurtzite GaN and ZnO in Fig. 18. Both Raman experiments have been executed similarly in the transparency regime (532 nm) on a -oriented single crystals. The response stems from within the focus depth which is large compared to $\lambda/\Delta n$; in this

Figure 18 (a) Raman scattering intensity for a -oriented GaN (A_1 -mode) in parallel-polarized configuration as a function of angle of incoming polarization. Experimental data (symbols) taken from [126] and fits (solid lines) for $\xi = 0, \pi/2$ and $\pi, \pi/2$ describing obviously correctly the limit of large excitation depth. (b) Same for a -ZnO, experimental data from [74].

case the apparent angle between (in short) the effective Raman tensor elements a and b , which is more precisely defined in [74], is $\xi = \pi/2$. This apparent angle has the same effect on the Raman intensity as the ad hoc phase parameters introduced in some publications [70–72], but has a strict physical meaning. An important and yet unexplored point is that for thin films, ξ takes values between 0 (or π , depending of the relative signs of the tensor elements) and around $\pi/2$ [74], and experiments allow to determine either the film thickness for known birefringence or Δn for known film thickness.

5.3 Biaxial Crystals The approach with ad hoc phase parameters completely fails for optically biaxial crystals. We demonstrate this for monoclinic Ga_2O_3 [127]. Despite up to three additional free parameters introduced by the relative phases, the agreement to experimental data is worse than for using the physically correct model [128]. If different crystal cuts are considered, the discrepancy becomes even more striking since the ad hoc parameters cannot explain the different intensities observed for identical polarization directions (indicated by colored lines in Fig. 19). For known dielectric tensor at the excitation wavelength

Figure 19 Raman scattering intensity for two selected phonon modes of β -Ga₂O₃ in various crystal orientations for parallel polarized (black) and cross-polarized (red) configurations; experimental data (symbols) and fits (solid lines). The maximum intensity for each phonon mode is scaled to 1. The vertical green and blue lines indicate the [102]- and [001]-direction, respectively

(532 nm, from [78]), these angular intensity patterns can be modeled consistently without additional parameters, allowing to determine the Raman tensor elements and their (relative) signs [128].

6 Summary and Outlook We have reviewed recent advances in the understanding of optically anisotropic crystals, namely the recently solved problem of modeling and interpreting Raman scattering intensities for excitation off a principal axis for arbitrary crystals, the dipole-based structure of the dielectric function due to lattice and electronic contributions and the dispersion of singular axes in the absorption regime. The transmission at an interface to a biaxial medium cannot be described with the current theory decomposing the wave in the biaxial medium into eigenstates.

Also particularities of microcavities with anisotropic cavity material, as composite systems from non-collinear uniaxial media, have been discussed. In such effectively biaxial system the complex energy dispersion has generally elliptically polarized eigenstates. We have predicted that modes in planar, anisotropic micro-cavities exhibit exceptional points (for suitable cavity thickness) and have demonstrated that in a (non-optimal) λ -cavity formed by a m-plane (Mg,Zn)O/ZnO heterostructure the two modes are non-orthogonal and partially coalesced.

We foresee these insights to bear fruit in the understanding of complex materials and the characterization of thin films and the modeling of photonic devices from optically anisotropic materials.

In the light of the literature review compiled here, W. Voigt should be given credit for the first description and analysis of what is now called *exceptional point*.

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7 Appendix

7.1 Formalism with Eigenstates in Biaxial Medium

The problem of reflection and transmission of planar waves at the planar interface to a biaxial medium has been treated, e.g. in [129–134], and also for computer graphics/ray tracing [135, 136], however without paying special attention to the singular directions. We consider here a wave incoming from vacuum. The dielectric tensor is rotated to describe the orientation of the biaxial medium and the components of the rotated tensor shall be denoted by ϵ_{ij} .

The wave vector of the incoming wave is $\mathbf{k} = (-\sin \alpha \sin \psi, \sin \alpha \cos \psi, \cos \alpha)$ (omitting the factor $k_0 = \omega/c_0$, and working with $|\mathbf{k}| = 1$), α being the angle of incidence relative to the interface normal $\mathbf{z}$, ψ being the azimuthal angle. The incoming wave shall be of type s (v- or TM-type) or type $p = \mathbf{k} \times \mathbf{s}$ (h- or TE-type) polarization. The reflected wave has the wave vector $\mathbf{k}' = (k_x, k_y, -k_z)$ and the vectors $\mathbf{s}' = \mathbf{s}$ and $\mathbf{p}' = -\mathbf{k}' \times \mathbf{s}$, the transmitted wave has the wave vectors $\mathbf{k}_a$ and $\mathbf{k}_b$ of the eigenstates and the related electrical field vectors $\mathbf{a}$ and $\mathbf{b}$.

One can follow the approach of [137] where the z -component of the a - and b -waves in the biaxial medium is found from $|G| = 0$ with

$$G = \begin{pmatrix} -[b_{yx} + b_{zx} b_{yz}/c_{xyz}] & c_{xzy} - b_{zy} b_{yz}/c_{xyz} \\ -[c_{yzx} - b_{zx} b_{xz}/c_{xyz}] & b_{xy} + b_{xz} b_{zy}/c_{xyz} \end{pmatrix}, \quad (6)$$

and [138]

$$b_{ij} = \epsilon_{ij} + k_i k_j \quad (7)$$

$$c_{ijk} = k_i^2 + k_j^2 - \epsilon_{kk}. \quad (8)$$

The four solutions of $|G| = 0$ represent two backward and two forward waves, the latter are taken as those with positive real parts $k_{a,z}$ and $k_{b,z}$. For a given in-plane field (E_x, E_y) the z -component of the electric field is then given by [137]

$$E_z = \frac{b_{zx} E_x + b_{zy} E_y}{c_{xyz}}. \quad (9)$$

The eigenvectors $\mathbf{a}$ and $\mathbf{b}$ are the (normalized) fields $\mathbf{E}_a$ (using $k_{a,z}$) and $\mathbf{E}_b$ (using $k_{b,z}$).

In the regions 1 (vacuum) and 2 (biaxial medium) the fields are

$$\mathbf{E}_1^s = \mathbf{s} \exp i\mathbf{k}\mathbf{r} + (R_{ss} \mathbf{s}' + R_{sp} \mathbf{p}') \exp i\mathbf{k}'\mathbf{r} \quad (10)$$

$$\mathbf{E}_2^s = X_{sa} \mathbf{a} \exp i\mathbf{k}_a \mathbf{r} + X_{sb} \mathbf{b} \exp i\mathbf{k}_b \mathbf{r} \quad (11)$$

$$\mathbf{E}_1^p = \mathbf{p} \exp i\mathbf{k}\mathbf{r} + (R_{ps} \mathbf{s}' + R_{pp} \mathbf{p}') \exp i\mathbf{k}'\mathbf{r} \quad (12)$$

$$\mathbf{E}_2^p = X_{pa} \mathbf{a} \exp i\mathbf{k}_a \mathbf{r} + X_{pb} \mathbf{b} \exp i\mathbf{k}_b \mathbf{r}. \quad (13)$$

The interface matching conditions for the s - and p -fields read

$$0 = \mathbf{z} \times (\mathbf{E}_1^\nu - \mathbf{E}_2^\nu) \quad (14)$$

$$0 = \mathbf{z} \times [\nabla \times (\mathbf{E}_1^\nu - \mathbf{E}_2^\nu)], \quad (15)$$

with $\nu = s, p$. The action of $\nabla \times$ on the exponentials is of the type $i\mathbf{k} \times$. The x - and y -components of the two equations (14) and (15) provide 4 equations for the 4 variables $(R_{ss}, R_{sp}, X_{sa}, X_{sb})$ and $(R_{ps}, R_{pp}, X_{pa}, X_{pb})$, respectively.

Although put forward in [130, 131] for non-absorbing crystals, this scheme has been used and elaborated in, e.g., Refs. [135, 137, 139] also for absorbing crystals. We note that for this case it fails on and in the vicinity of the singular axes since the vectors $\mathbf{a}$ and $\mathbf{b}$ are no longer orthogonal (cmp. Fig. 7). Thus the transmitted wave cannot be properly projected and the transmission coefficients take unphysically large values $\gg 1$, eventually diverging on the singular axes.

7.2 Propagation-Formalism In order to avoid the problem of decomposing the field in the biaxial medium into eigenmodes we first follow the idea of the Berreman formalism [140, 141]. We start from the Maxwell equations (in the absence of currents and free charges) $\nabla \times \mathbf{E} = -\dot{\mathbf{B}}$ and $\nabla \times \mathbf{H} = \dot{\mathbf{D}}$ together with the special material equations $\mathbf{D} = \epsilon_0 \epsilon \mathbf{E}$ (The dielectric tensor ϵ is given in the (x, y, z) coordinates of the reflection geometry) and

$\mathbf{B} = \mu_0 \mathbf{H}$ (nonmagnetic material). The periodicity in space and time of the fields shall be $\exp i(k_x x - \omega t)$. The curl operator is written as matrix $\mathbf{C}$

$$\mathbf{C} = \begin{pmatrix} 0 & -\partial_z & \partial_y \\ \partial_z & 0 & -\partial_x \\ -\partial_y & \partial_x & 0 \end{pmatrix} = \begin{pmatrix} 0 & -\partial_z & 0 \\ \partial_z & 0 & -ik_x \\ 0 & ik_x & 0 \end{pmatrix}, \quad (16)$$

using the substitutions $\partial_x = ik_x$ and $\partial_y = 0$. We set up equations for a six-component vector $(\mathbf{E}, \mathbf{H}')$ with $\mathbf{H}' = \mu_0 c \mathbf{H}$, and arrive at (in 3×3 block matrix form)

$$\begin{pmatrix} \mathbf{0} & \mathbf{C} \\ -\mathbf{C} & \mathbf{0} \end{pmatrix} \begin{pmatrix} \mathbf{E} \\ \mathbf{H}' \end{pmatrix} = \begin{pmatrix} \epsilon & \mathbf{0} \\ \mathbf{0} & \mathbf{1} \end{pmatrix} \begin{pmatrix} \mathbf{E} \\ \mathbf{H}' \end{pmatrix}. \quad (17)$$

The algebraic third and sixth row yield E_z and H'_z in terms of the other field components. Eventually we find for the four-component vector Ψ of the tangential field components $\mathbf{E}_T = (E_x, E_y)$ and $\mathbf{H}'_T = (H'_x, H'_y)$, $\Psi = (E_x, E_y, H'_x, H'_y)$:

$$\frac{\partial}{\partial z} \Psi = ik_0 \mathbf{\Gamma} \Psi, \quad (18)$$

with $k_0 = \omega/c_0$, $k_x = k_0 \sin \alpha$, α being the angle of incidence relative to the surface normal, and the matrix $\mathbf{\Gamma} =$

$$\begin{pmatrix} \frac{\epsilon_{zx} \sin \alpha}{\epsilon_{zz}} & \frac{\epsilon_{zy} \sin \alpha}{\epsilon_{zz}} & 0 & 1 - \frac{\sin^2 \alpha}{\epsilon_{zz}} \\ 0 & 0 & -1 & 0 \\ \frac{\epsilon_{yz} \epsilon_{zx}}{\epsilon_{zz}} - \epsilon_{yx} \sin^2 \alpha + \frac{\epsilon_{yz} \epsilon_{zy}}{\epsilon_{zz}} & -\epsilon_{yy} & 0 & -\frac{\epsilon_{yz} \sin \alpha}{\epsilon_{zz}} \\ -\frac{\epsilon_{xz} \epsilon_{zx}}{\epsilon_{zz}} + \epsilon_{xx} & -\frac{\epsilon_{xz} \epsilon_{zy}}{\epsilon_{zz}} + \epsilon_{xy} & 0 & \frac{\epsilon_{xz} \sin \alpha}{\epsilon_{zz}} \end{pmatrix}, \quad (19)$$

similar to the result in [142]. Thus for a slab of homogeneous material and thickness d the fields between entry ($z = 0$) and exit ($z = d$) are related by

$$\Psi(0) = \exp(-ik_0 d \mathbf{\Gamma}) \Psi(d) = \mathbf{P} \Psi(d). \quad (20)$$

The 4×4 propagation matrix $\mathbf{P}$ shall be written with 2×2 block matrices $\mathbf{P}_i$,

$$\mathbf{P} = \begin{pmatrix} \mathbf{P}_1 & \mathbf{P}_2 \\ \mathbf{P}_3 & \mathbf{P}_4 \end{pmatrix}. \quad (21)$$

For the simulations executed in this paper the `MatrixExp` function of Mathematica [76] has been used for the evaluation of $\mathbf{P}$.

The (normalized) electromagnetic wave impinging from vacuum onto the surface has the wave vector $\mathbf{k} = k_0 (\sin \alpha, 0, \cos \alpha) = k_0 \hat{\mathbf{k}}$. The relation between the electrical and magnetic fields in vacuum are $\mathbf{H}^i = \hat{\mathbf{k}} \times \mathbf{E}^i$ and $\mathbf{E}^i = -\hat{\mathbf{k}} \times \mathbf{H}'^i$, from which follows the impedance matrix $\mathbf{Z}$ (det $\mathbf{Z}=1$)

$$\mathbf{E}_T^i = \begin{pmatrix} 0 & \cos \alpha \\ -\frac{1}{\cos \alpha} & 0 \end{pmatrix} \begin{pmatrix} H_x'^i \\ H_y'^i \end{pmatrix} = \mathbf{Z} \mathbf{H}_T'^i, \quad (22)$$

and at the top surface ($z = 0$):

$$E_T^i(0) = Z H_T'^i(0), \quad (23)$$

accordingly for the reflected and transmitted waves [143]

$$E_T^r(0) = -Z H_T'^r(0) \quad (24)$$

$$E_T^t(d) = Z H_T'^t(d). \quad (25)$$

We note that the theory is valid for all angles of incidence α ; in this paper only normal incidence is considered, obviously then

$$Z = \begin{pmatrix} 0 & 1 \\ -1 & 0 \end{pmatrix}. \quad (26)$$

Reflection and transmission are described by the matrices R and T ,

$$E_T^r(0) = R E_T^i(0) \quad (27)$$

$$E_T^t(d) = T E_T^i(0), \quad (28)$$

and from (20) eventually it is found [143]

$$R = [P_1 Z + P_2 - Z(P_3 Z + P_4)] \quad (29)$$

$$[P_1 Z + P_2 + Z(P_3 Z + P_4)]^{-1} \quad (30)$$

$$T = 2Z [P_1 Z + P_2 + Z(P_3 Z + P_4)]^{-1}. \quad (31)$$

With varying slab thickness d , the transmission and reflection exhibit thickness (Fabry-Pérot type) oscillations. In the case of absorption these die out if the thickness is large compared to the absorption length. Then the reflectivity value for a thick layer can be obtained. The transmitted intensity contains the mode conversion during the propagation in the slab.

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